

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IXTP120N075T2

D FEATURES · Static drain-source on-resistance: $R_{DS}(on) \le 7.7 m_{\Omega} @V_{GS} = 10V$ · Fully characterized avalanche voltage and current 100% avalanche tested Minimum Lot-to-Lot variations for robust device pin 1, Gate performance and reliable operation 2, Drain 123 3, Source TO-220C package APPLICATION DC/DC Converters S · High Current Switching Applications ABSOLUTE MAXIMUM RATINGS(Ta=25°C) SYMBOL PARAMETER VALUE UNIT VDSS **Drain-Source Voltage** 75 V V V_{GS} Gate-Source Voltage ± 20 Drain Current-Continuous 120 I_D А с Drain Current-Single Pulsed 300 А **I**DM mm DIM MIN MAX P_{D} Total Dissipation @Tc=25°C 250 W 15.90 15.50 А 9.90 10.20 В **Operating Junction Temperature** -55~175 °C С 4.20 4.50 Τį D 0.70 0.90F 3.40 3.70 Storage Temperature -55~175 °C G Tstg 4.98 5.18Н 2.68 2.90J 0.44 0.60 13.00 K 13.40 THERMAL CHARACTERISTICS 1.10 1.45 L 2.70 Q 2.90

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SYMBOL	PARAMETER	MAX	UNIT		
R _{th(j-c)}	Junction-to-case thermal resistance	0.6	°C/W		

2.30

1.29

6.45

8.66

R

S

U

v

2.70

1.35

6.65

8.86

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ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID = 250 μ A	75		V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID = 250 μ A	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 60A		7.7	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±200	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V		5	- μ Α
		V _{DS} = V _{DSS} ; V _{GS} = 0V;TJ= 150℃		150	
V _{SD}	Diode forward voltage	I _F = 98A; V _{GS} = 0V		1.5	V

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